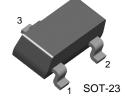


BC807/BC808

Switching and Amplifier Applications

- Suitable for AF-Driver stages and low power output stages
- Complement to BC817/BC818



1. Base 2. Emitter 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CES}	Collector-Emitter Voltage		
020	: BC807	-50	V
	: BC808	-30	V
V _{CEO}	Collector-Emitter Voltage		
	: BC807	-45	V
	: BC808	-25	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current (DC)	-800	mA
P _C	Collector Power Dissipation	-310	mW
P _C	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

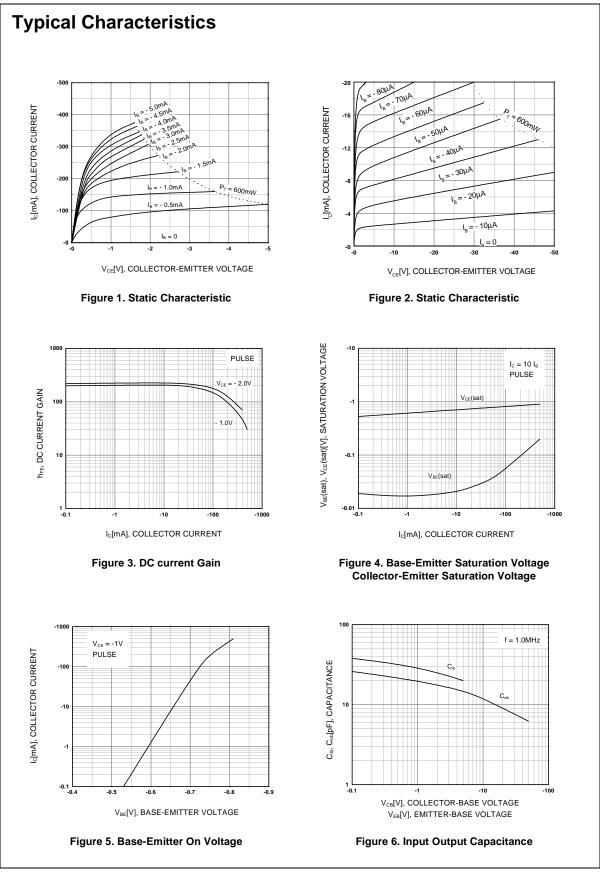
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = -10mA, I _B =0				
	: BC807		-45			V
	: BC808		-25			V
BV _{CES}	Collector-Emitter Breakdown Voltage	I _C = -0.1mA, V _{BE} =0				
	: BC807		-50			V
	: BC808		-30			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I_{E} = -0.1mA, I_{C} =0	-5			V
I _{CES}	Collector Cut-off Current	V _{CE} = -25V, V _{BE} =0			-100	nA
I _{EBO}	Emitter Cut-off Current	V_{EB} = -4V, I_{C} =0			-100	nA
h _{FE1}	DC Current Gain	V _{CE} = -1V, I _C = -100mA	100		630	
h _{FE2}		$V_{CE} = -1V, I_{C} = -300 \text{mA}$	60			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I_{C} = -500mA, I_{B} = -50mA			-0.7	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = -1V, I_{C} = -300 \text{mA}$			-1.2	V
f _T	Current Gain Bandwidth Product	V_{CE} = -5V, I_{C} = -10mA f=50MHz		100		MHz
C _{ob}	Output Capacitance	V _{CB} = -10V, f=1MHz			12	pF

$h_{\mbox{\scriptsize FE}}$ Classification

Classification	16	25	40
h _{FE1}	100 ~ 250	160 ~ 400	250 ~ 630
h _{FE2}	60-	100-	170-

Marking Code

Туре	807-16	807-25	807-40	808-16	808-25	808-40
Marking	9FA	9FB	9FC	9GA	9GB	9GC



Typical Characteristics (Continued)

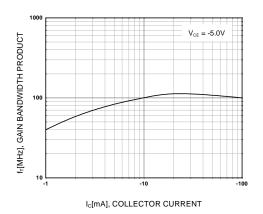
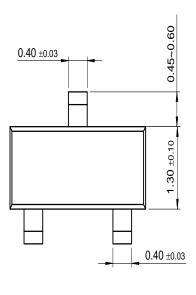
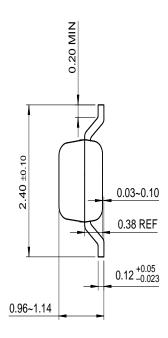


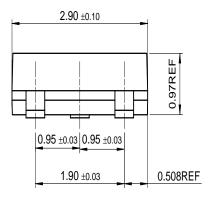
Figure 7. Current Gain Bandwidth Product

Package Dimensions

SOT-23







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
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E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C™	OCXTM	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franchise™		OPTOLOGIC [®]	SILENT SWITCHER®	VCX^{TM}
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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